

## **JW77156D**

## 60V, 13mΩ Synchronous Rectifier

Preliminary Specifications Subject to Change without Notice

#### **DESCRIPTION**

JW77156D is a synchronous rectifier, used for the secondary side rectification of Flyback. By driving an internal MOSFET, JW77156D is able to significantly improve the efficiency comparing with the conventional Diode rectifier.

When JW77156D senses  $V_{DS}$  of internal MOSFET less than -300mV, it turns on the internal MOSFET. Once the  $V_{SW}$  is greater than -10mV, JW77156D turns off the internal MOSFET.

JW77156D supports multiple operation modes, such as DCM, CrCM, CCM and Quasi-Resonant. By implementing the Joulwatt proprietary technology, JW77156D is able to handle CCM operation.

JW77156D is available in ESOP-8 package.

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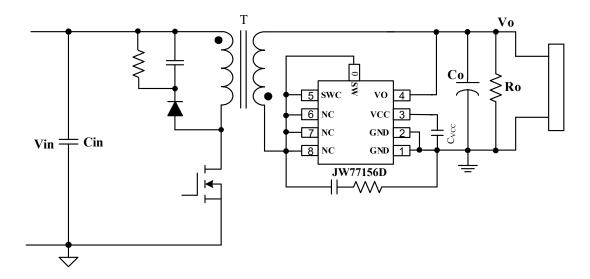
#### **FEATURES**

- Supports DCM, Quasi-Resonant, CrCM and CCM operation
- Support the Flyback topology
- Output voltage directly supply VCC
- Low quiescent current
- Under-voltage protection
- Fast driver capability for CCM operation
- ESOP-8 package

#### **APPLICATIONS**

- Flyback converter
- 18W/20W quick charge adaptor

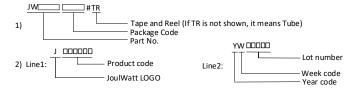
#### TYPICAL APPLICATION



#### **ORDER INFORMATION**

DEVICE <sup>1)</sup>	PACKAGE	TOP MARKING <sup>2)</sup>	ENVIRONMENTAL <sup>3)</sup>	
JW77156DESOP#TR	ESOP8	J77156D	Green	
		$YW\Box\Box\Box\Box$		

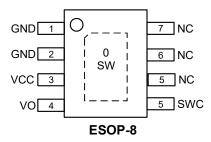
#### Notes:



<sup>3)</sup> All JoulWatt products are packaged with Pb-free and Halogen-free materials and compliant to RoHS standards.

#### **PIN CONFIGURATION**

#### **TOP VIEW**



# ABSOLUTE MAXIMUM RATING1)

SW Pin	60V
SWC Pin	60V
VO Pin	28V
VCC Pin	6.5V
Junction Temperature <sup>2) 3)</sup>	150°C
Storage Temperature	65°C to 150°C
Lead Temperature (Soldering, 10sec.)	260°C
Continuous Power Dissipation (TA = +25 °C) <sup>4)</sup> ESOP-8	2.5W

#### RECOMMENDED OPERATING CONDITIONS

SW Pin	4.7V to 48V
SWC Pin	4.7V to 48V
VO Pin	2.5V to 20V
VCC Pin	4.5V to 6.4V
Operation Junction Temperature	40°C to 125°C
THERMAL PERFORMANCE <sup>5)</sup>	$ heta_{J\!A} \qquad  heta_{J\!c}$
ESOP8	5010°C/W

#### Note:

1) Exceeding these ratings may damage the device. These stress rating do not imply function operation of the device at any other conditions beyond those indicated under RECOMMENDED OPERATING CONDITIONS.

- 2) Continuous operation over the specified absolute maximum operating junction temperature may damage the device.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) The maximum allowable continuous power dissipation at any ambient temperature is calculated by  $P_D(MAX)=(T_J(MAX)-T_A)/\theta_{JA}$ .
- **5)** Measured on JESD51-7, 4-layer PCB.

#### **ELECTRICAL CHARACTERISTICS**

 $T_A$  = 25°C, unless otherwise stated

Advance Information, not production data, subject to change without notice.

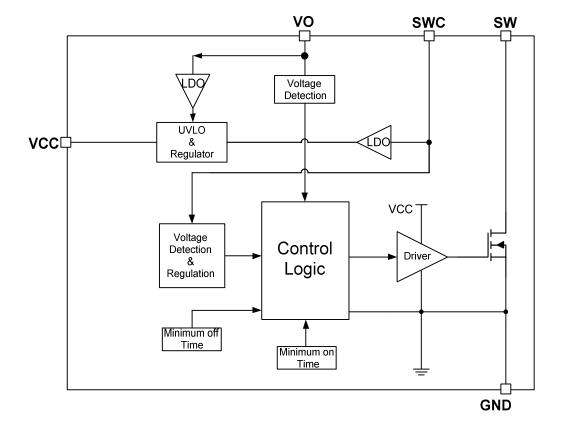
Item	Symbol Condition		Min.	Тур.	Max.	Units			
VCC Section									
VCC Voltage	VCC	SW=40V, VCC=2.2uF		5.8		V			
VCC Startup Voltage	V <sub>CC_Startup</sub>			4.05		V			
VCC UVLO	V <sub>CC_UVLO</sub>			3.95		V			
Quiescent Current	Iq	VCC=4.5V, VCC=2.2uF		24		uA			
Internal Driver Section									
Internal Gate Pull up Current 6)	I <sub>GU</sub>	GT=1V		0.65		Α			
Internal Gate Pull down Current 6)	Igo	GT=5V		4.7		Α			
Internal Gate Minimum on Time 6)	T <sub>MIN_ON</sub>			1.3		uS			
Internal Gate Minimum off Time <sup>6)</sup>	T <sub>MIN_OFF</sub>			700		nS			
Turn-on Total Delay <sup>6)</sup>	T <sub>DON</sub>			84		nS			
Turn-off Total Delay 6)	T <sub>DOF</sub>			22.4		nS			
SWC and VO Section									
Internal MOSFET Turn on Threshold <sup>6)</sup>	V <sub>SW_ON</sub>			-300		mV			
Internal MOSFET Turn off Threshold <sup>6)</sup>	V <sub>SW_OFF</sub>			-10		mV			
Internal MOSFET Turn off Threshold in MOT <sup>6)</sup>	Vsw_off_mot			+150		mV			
SW Control Voltage <sup>6)</sup>	V <sub>SW_REG</sub>			-40		mV			
SW Control Voltage MAX <sup>6)</sup>	V <sub>SW_REG_MAX</sub>			-170		mV			
VO Enable Charge Voltage	V <sub>O_EN</sub>	VCC=4V, SW=0V		4.55		V			
VO Disable Charge Voltage	Vo_dis	VCC=4V, SW=0V		4.35		V			
VCC Charge Current	I <sub>CV</sub>	SW=40V, VCC=4V		44		mA			
VO Charge Current	Ivo_chg	SW=0V, VCC=4V, VO=5V		20		mA			
Vo Short-circuit Detection Voltage	Vo_short		1.8	2.1	2.3	V			
Internal MOSFET Section									
Internal MOSFET Rdson <sup>6)</sup>	Rdson			13		m Ω			
Breakdown Voltage	B <sub>(BR)DSS</sub>		60			V			

<sup>6)</sup> Guaranteed by design.Not tested in production.

## **PIN DESCRIPTION**

Pin No.	Name	Description				
1,2	GND	Power Ground.				
3	VCC	Power supply. Bypass a Capacitor Between VCC and GND.				
4	VO	Output Voltage Sensing and Charging to VCC.				
5	SWC	Internal Power MOSFET Drain Voltage Sensing. Charging to VCC.				
6,7,8	NC	NC				
0	SW	Internal Power MOSFET Drain.				

## **BLOCK DIAGRAM**



#### **FUNCTIONAL DESCRIPTION**

#### Operation

JW77156D is a synchronous rectifier which combined with internal MOSFET can replace the Schottky Barrier Diode. It supports all operations, such as DCM, CrCM, (Quasi-Resonant) and CCM when adopted in flyback converter.

#### **Startup**

During the startup period, when the VCC is lower than startup voltage, the external MOSFET is turned off. The current flows though body diode before the VCC reaches to the startup voltage Vcc startup.

#### **Under-Voltage Lockout (UVLO)**

When the VCC is below UVLO threshold, the external MOSFET is turned off and pulled low internally. Once the VCC exceeds the startup voltage Vcc\_startup, the parts is activated again.

### **LDO Charging Logic**

JW77156D have two internal LDO to charge the VCC pin. When VO is lower than 4.35V, JW77156D can power itself through the internal LDO connected to SWC pin during the SR turn-off period, which means primary the primary side MOSFET is turned on and SWC presents a positive voltage. A capacitor between VCC and GND is required to store the energy and supply to IC during the SR turn-on period.

The other internal LDO is connected from VO to

VCC, it charges VCC pin when VO is higher than 4.55V.

#### **Turn On Phase**

When the synchronous MOEFET is conducting, current flows through the body diode of MOSFET, which generates a negative voltage  $V_{SW}$  across it. When  $V_{SW}$  is lower than  $V_{MOS\_ON}$ , the part will pull the internal gate high to turn on the synchronous MOSFET after turn on delay time  $T_{DON}$ .

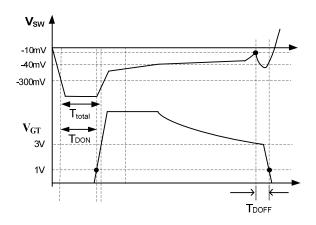


Figure-1 Turn on delay and turn off delay

#### **Conducting Phase**

When the synchronous MOSFET is turn on, the drain source voltage  $V_{SW}$  it is determined by its on resistance and the current through it. The part adjusts the gate voltage and regulates the Vsw to a internal threshold (typical -40mV) after the synchronous MOSFET turn on. When the  $V_{SW}$  is lower than -40mV, the gate keep its maximum voltage. And the synchronous MOSFET is fully on.

The control circuit contains a minimum on time function. The  $V_{SW}$  voltage may have a parasitic ring when the synchronous MOSFET turns on. So a minimum on time (MOT) is very important

to avoid the MOSFET turn off threshold is false triggered. During the minimum time, the gate can still be turned off if  $V_{SW}$  touches a positive threshold value, +150mV.

#### **Turn Off Phase**

After synchronous MOSFET conducting, once the voltage  $V_{SW}$  touches the MOSFET turn off threshold (-10mV), the internal gate is pulled to low after a turn off delay time  $T_{DOFF}$ . A 700nS blanking time is necessary to avoid error trigger.

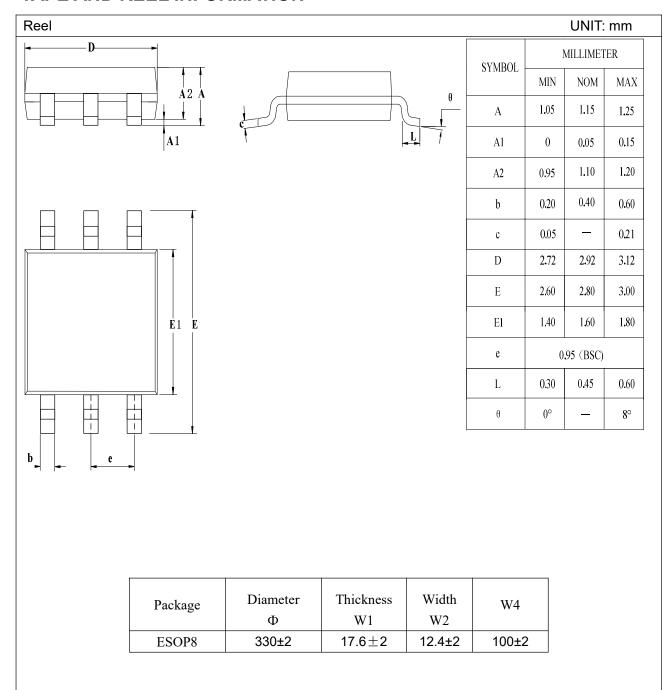
#### Minimum On-time (MOT)

MOT stands for the minimum on time of synchronous MOSFET. For JW77156D, MOT is about 1.3uS.

#### **Output Voltage Detection**

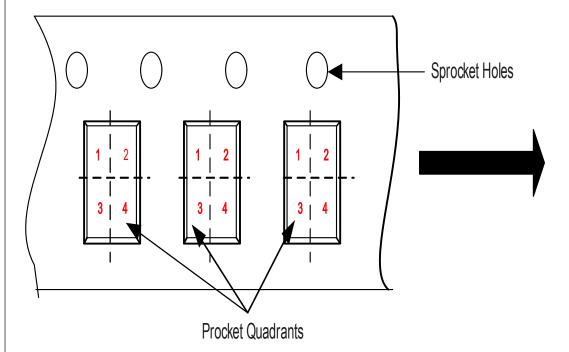
The JW77156D has output voltage detection function via VO pin. To avoid the gate error turn on during starting-up period, the whole SR control logic is disabled when the VO voltage is lower than 2.1V. VCC is charged from VO pin when VO is higher than 4.55V to save power loss caused by the LDO when charging from SWC pin to VCC pin.

#### TAPE AND REEL INFORMATION



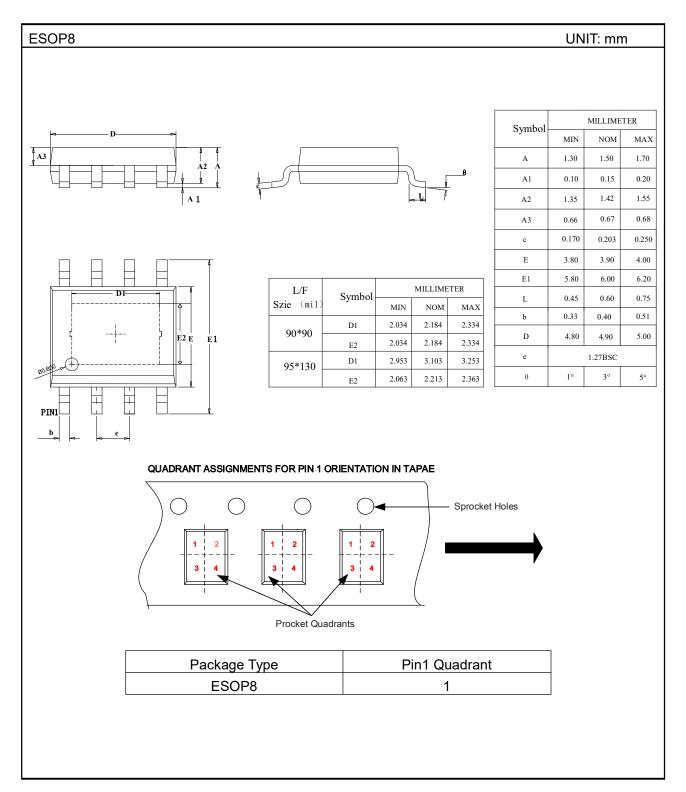
Carrier Tape UNIT: mm

# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPAE



Package		Tape dimensions (mm)										
	P0	P2	P1	A0	В0	W	Т	K0	Ф1	Ф2	Е	F
ESOP8	4.0±0.1	2.0±0.1	8.0±0.1	6.40±0.3	5.35±0.3	12.0±0.3	0.25±0.2	2.00±0.2	1.50min	1.50min	1.75±0.1	5.50±0.10

## **PACKAGE OUTLINE**



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